



# 10-B  
Amended  
H. Shakeri  
4-1002

PATENT  
Attorney Docket No. 99154X204201

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Fang et al.

Application No. 09/595,227

Filed: June 16, 2000

Art Unit: 3723

Examiner: H. Shakeri

For: METHOD FOR POLISHING A  
MEMORY OR RIGID DISK WITH A  
PHOSPHATE ION-CONTAINING  
POLISHING SYSTEM

RECEIVED  
MAR 5 2002  
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RESPONSE TO OFFICE ACTION

Commissioner for Patents  
Washington, D.C. 20231

Dear Sir:

In response to the Office Action dated February 15, 2002, please enter the following amendments and consider the following remarks.

AMENDMENTS

IN THE CLAIMS:

Please cancel claims 24-34 without prejudice.

Replace the indicated claims with:

B1  
1. (Amended) A method for planarizing or polishing a surface of a memory or rigid disk comprising abrading at least a portion of the surface with a polishing system comprising (i) a polishing composition comprising water, an oxidizing agent, and about 0.04 M or higher phosphate ion or phosphonate ion, and (ii) abrasive material.

REMARKS

The Present Invention

The present invention relates to a method of planarizing or polishing the surface of a memory or rigid disk. Claims 1-23 are pending.